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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Small Signal Product

300mW, NPN Small Signal Transistor

FEATURES

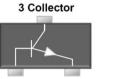
- Epitaxial planar die construction
- Surface device type mounting
- Moisture sensitivity level 1
- Matte Tin (Sn) lead finish with Nickel (Ni) underplate
- Pb free version and RoHS compliant
- Packing code with suffix "G" means green compound (halogen-free)

MECHANICAL DATA

- Case: SOT- 23, molded plastic
- Terminal: Matte tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- High temperature soldering guaranteed: 260°C/10s
- Weight: 8 mg (approximately)
- Marking Code: 1E.









1 Base	2 Emitte	

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)				
PARAMETER	SYMBOL	VALUE	UNIT	
Power Dissipation	P _D	300	mW	
Collector-Base Voltage	V _{CBO}	60	V	
Collector-Emitter Voltage	V_{CEO}	40	V	
Emitter-Base Voltage	V_{EBO}	6	V	
Collector Current	I _C	200	mA	
Junction and Storage Temperature Range	T_J , T_{STG}	-55 to +150	°C	

Notes: Valid provided that electrodes are kept at ambient temperature

PARAMETER				SYMBOL	MIN	MAX	UNIT
Collector-Base Breakdown Voltage		I _C = 10 μA	I _E = 0	V _{(BR)CBO}	60	-	V
Collector-Emitter Breakdo	own Voltage	I _C = 1 mA	I _B = 0	V _{(BR)CEO}	40	-	V
Emitter-Base Breakdown	Voltage	I _E = 10 μA	I _C = 0	V _{(BR)EBO}	6	-	V
Collector Cut-off Current		V _{CB} = 60 V	I _E = 0	I _{CBO}	-	0.1	μA
Collector Cut-off Current		V _{CE} = 30 V	$V_{BE(OFF)} = 3 V$	I _{CEO}	-	50	nA
Emitter Cut-off Current		V _{EB} = 5 V	I _C = 0	I _{EBO}	-	0.1	μΑ
		V _{CE} = 1 V	I _C = 10 mA		100	400	
DC Current Gain		$V_{CE} = 1 V$	$I_C = 50 \text{ mA}$	h _{FE}	60	-	
		$V_{CE} = 1 V$	$I_C = 100 \text{ mA}$		30	-	
Collector-Emitter Saturation	on Voltage	$I_C = 50 \text{ mA}$	I _B = 5 mA	V _{CE(sat)}	-	0.3	V
Base-Emitter Saturation \	/oltage	$I_C = 50 \text{ mA}$	I _B = 5 mA	V _{BE(sat)}	-	0.95	V
Transition frequency	V _{CE} = 20 V	I _C = 10 mA	f= 100MHz	f _T	250	-	MHz
Delay time	V _{CC} = 3 V	V _{BE} = 0.5 V	I _C = 10 mA	t _d	-	35	ns
Rise time			$I_{B1} = 1.0 \text{ mA}$	t _r	-	35	ns
Storage time		V _{CC} = 3 V	I _C = 10 mA	t _s	-	200	ns
Fall time		$I_{B1} = I_{B2} = 1.0$	mA	t _f	-	50	ns

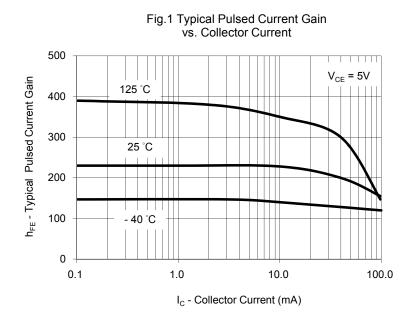
- 40 °C



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RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)



vs. Collector Current $\beta = 10$ $125 ^{\circ}C$ $25 ^{\circ}C$

Fig. 2 Collector-Emitter Saturation Voltage

0.20

0.15

0.10

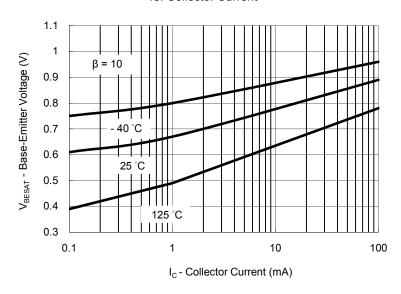
0.05

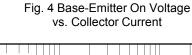
0.00

V _{CESAT}- Collector-Emitter Voltage (V)

I_C - Collector Current (mA)

Fig. 3 Base-Emitter Saturation Voltage vs. Collector Current





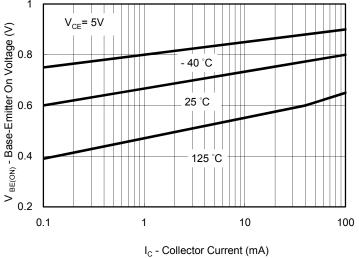


Fig. 5 Collector-Cutoff Current vs. Ambient Temperature

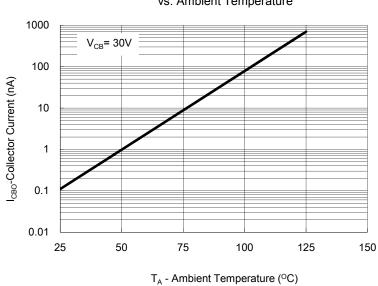


Fig. 6 Capacitance vs.
Reverse Bias Voltage

10

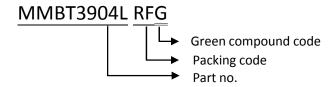
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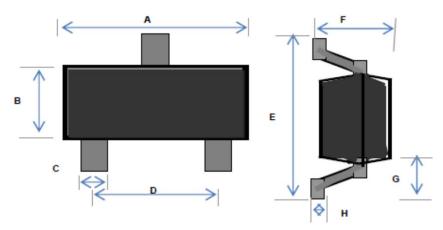
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ORDER INFORMATION (EXAMPLE)



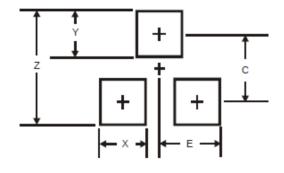
PACKAGE OUTLINE DIMENSIONS

SOT-23



DIM.	Unit(mm)		Unit(inch)	
DIIVI.	Min	Max	Min	Max
Α	2.70	3.10	0.106	0.122
В	1.10	1.50	0.043	0.059
С	0.30	0.51	0.012	0.020
D	1.78	2.04	0.070	0.080
Е	2.10	2.64	0.083	0.104
F	0.89	1.30	0.035	0.051
G	0.55 REF		0.022	REF
Н	0.10 REF		0.004	REF

SUGGEST PAD LAYOUT



DIM	Unit (mm)	Unit (inch)	
DIIVI	TYP	TYP	
Z	2.90	0.114	
X	0.80	0.031	
Y	0.90	0.035	
С	2.00	0.079	
Е	1.35	0.053	







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Document Number: DS_S1501029 Version: A15